

R8A66155SP 16-bit I/O EXPANDER WITH LED DRIVE FUNCTION

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DESCRIPTION

R8A66155 is a semiconductor integrated circuit which has 16-bit shift register function to execute serial in - parallel out conversion and parallel in - serial out conversion.

Built in two shift registers for serial in - parallel out and parallel in - serial out are constructed independently, This IC is able to read serial input data into a shift register while output the serial data converting from the parallel data input.

Also, parallel data I/O pins can be set to input mode or output mode by a bit.

R8A66155 is useful in a wide range of applications, such as MCU (micro controller unit) I/O port extension and serial bus system data communication.

Moreover, R8A66155 can be used as the anode common LED drive, too.

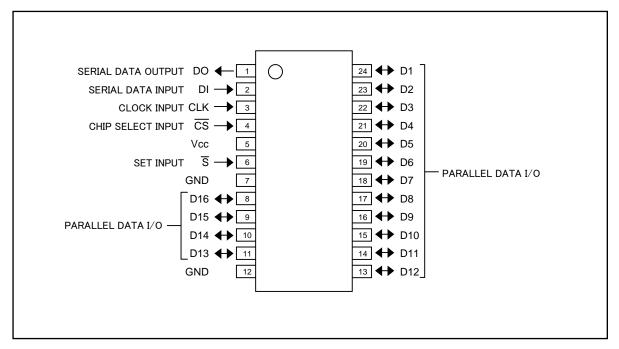
FEATURES

- Bi-directional serial communication with MCU
- Serial data can be input during parallel to serial data conversion
- Parallel data I/O pins can be set input mode or output mode by a bit
- Schmitt input (DI, CLK, /S, /CS)
- N-ch open drain output (DO, D1~D16).
 High output current IoL=24mA (at Vcc=4.5V), IoL=15mA (at Vcc=3.0V)
- Parallel data I/O pins (D1~D16)
- Wide supply voltage range (Vcc=2.0 to 6.0V)
- Wide operating temperature range (Ta=-40 to 85°C)

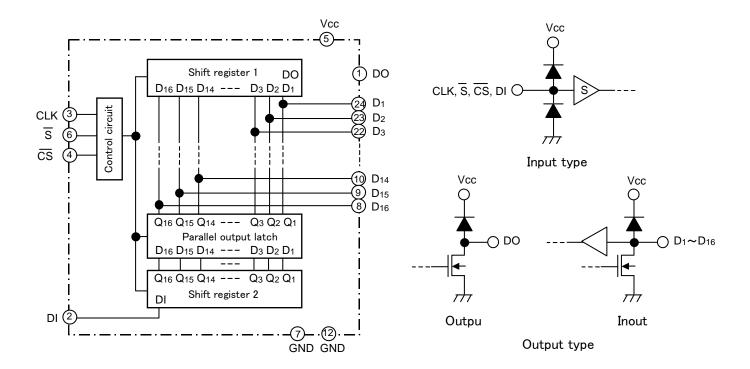
APPLICATION

- Serial parallel or parallel serial data conversion for MCU peripheral.
- Serial bus control by MCU.
- LED array drive, The various LED display modules.

PIN CONFIGURATION (TOP VIEW)



BLOCK DIAGRAM



FUNCTION

The R8A66155 is produced by using the silicon gate CMOS technology and has low power dissipation and high noise margin.

Built in two shift registers for serial in-parallel out (Shift register 2) and parallel in-serial out (Shift register 1) are constructed independently, R8A66155 is able to read serial input data into a shift register while output the serial data converting from the parallel data input.

Serial output operation of 16-bit parallel latched data and serial input operation from MCU are started when /CS is changed from "H" to "L".

16-bits parallel data are latched by the negative edge of /CS and are output from the DO terminal synchronously to the negative edge of CLK, and also the DI terminal read serial input data from MCU and are written into the internal shift register 2.

The 17th and following shift clock pulse are ignored and serial input data is masked, and DO terminal becomes high-impedance ("High-Z").

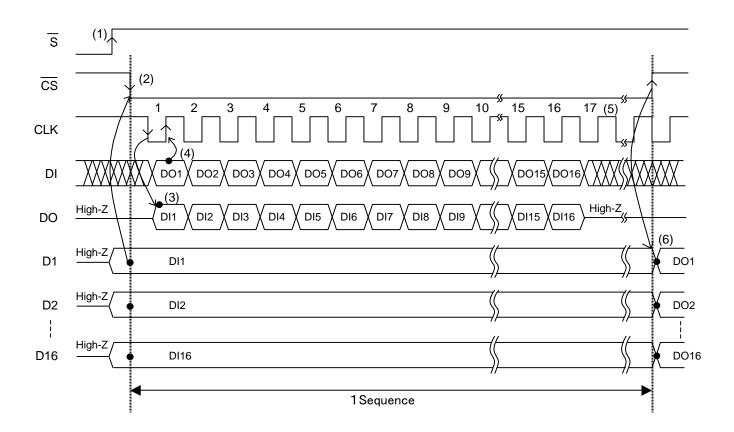
When /CS is changed from "L" to "H", 16-bits serial data which is read from the DI terminal are output to the D1~D16 terminals as parallel data.

As the output circuit type of D1~D16 terminals is N-ch open drain output, write data "H" for pins which should be set to input mode.

DESCRIPTION OF OPERATION

- (1) When power ON, the status of DO and D1~D16 terminals are not determined. These terminals are turn to high-impedance when "L" is input to the /S terminal.
- (2) By the negative edge of /CS, the status of D1~D16 terminals is loaded on shift register 1.
- (3) Synchronous to the negative edge of CLK, 16-bit loaded data is serial output from the DO terminal.
- (4) Synchronous to the positive edge of CLK, 16-bit serial input data from DI is written into the shift register 2.
- (5) The 17th and following shift clock pulse are ignored and the serial data input operation is stopped. And the DO terminal becomes high-impedance ("High-Z").
- (6) By the positive edge of /CS, input data described in (4) is output to D1~D16 terminals.
- (7) Shift register 1 loads the AND tie data of external parallel input data and latched data on parallel output latch.
- (8) If the /CS is changed from "L" to "H" before reaches the 16th bit of CLK, parallel output latch latches data which has been written on shift register 2 and output it to D1~D16 terminals. Serial data after this since is ignored and the DO terminal becomes high-impedance.
- (9) Input/output mode set to D1~D16 terminals is done by the serial input data to the DI terminal. Terminals which "H" is written are set to input, and "L" is written are set to output.

OPERATION TIMING CHART



ABSOLUTE MAXIMUM RATINGS (Ta=-40~85°C, unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
VCC	Supply voltage		-0.5 ~ +7.0	V
VI	Input voltage		-0.5 ~ Vcc+0.5	V
Vo	Output voltage		-0.5 ~ Vcc+0.5	V
Ю	Output current per output pin		50	mA
ICC	Supply / GND current	VCC, GND	430	mA
Pd	Power dissipation	(Note)	500	mW
Tstg	Storage temperature range		-65 ~ 150	°C

Note: R8A66155SP: Ta=-40~+75°C. Ta=75~85°C are derated at -8 mW/°C.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Unit		
Symbol	i alametei	Min.	Тур.	Max.	Offic
Vcc	Supply voltage	2.0		6.0	V
VI	Input voltage	0		Vcc	V
VO	Output voltage	0		Vcc	V
Topr	Operating temperature range	-40		85	°C

ELECTRICAL CHARACTERISTICS

(Vcc=2.0~6.0V, Ta=-40~85°C, unless otherwise noted)

Symbol	Parameter		Test conditions		Limits		
Symbol	Faiailletei	1621 001	iditions	Min.	Тур.	Max.	Unit
VT+	Positive going threshold voltage (*1)			0.35 x Vcc		0.80 x Vcc	٧
VT-	Negative going threshold voltage (*1)	Vo=0.1V, Vcc-0.1V I lo I=20uA		0.20 x Vcc		0.65 x Vcc	V
VIH	"H" input voltage (*2)			0.75 x Vcc			V
VIL	"L" input voltage (*2)					0.25 x Vcc	V
VOL	"L" output voltage	VI=VT+,VT- Vcc=4.5V	IOL=24mA			0.5	V
		VI=VT+,VT- Vcc=3.0V	IOL=15mA			0.5	V
		VI=VT+,VT- Vcc=2.0V	IOL=8mA			0.3	V
Ю	Output leakage current	Vcc=6V	Vo=Vcc			10	uA
Ю	Output leakage current	VCC=6 V	Vo=GND			-10	uA
IIH	"H" input current	VI=Vcc, Vcc=6V VI=GND, Vcc=6V				1	uA
IIL	"L" input current					-1	uA
Icc	Quiescent supply current	VI=Vcc, GNE Vcc=6V)			100	uA

*1 : DI, CLK, /CS, /S

*2: D1~D16



SWITCHING CHARACTERISTICS

(Vcc=2.0~6.0V, Ta=-40~85°C, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
Symbol			Min.	Тур.	Max.	Offic
fmax	Maximum repeat frequency				1.9	MHz
tPLZ	Output "L-Z" and "Z-L" propagation time				400	ns
tPZL	CLK - DO	CL=50pF			400	ns
tPLZ	Output "L-Z" and "Z-L" propagation time	RL=1kΩ			400	ns
tPZL	/CS - D1~D16	(note1)			400	ns
tPLZ	Output "L-Z" propagation time /S - DO, /S - D1~D16				400	ns

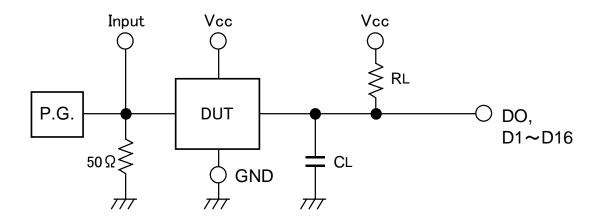
TIMING REQUIREMENTS

(Vcc=2.0~6.0V, Ta=-40~85°C, unless otherwise noted)

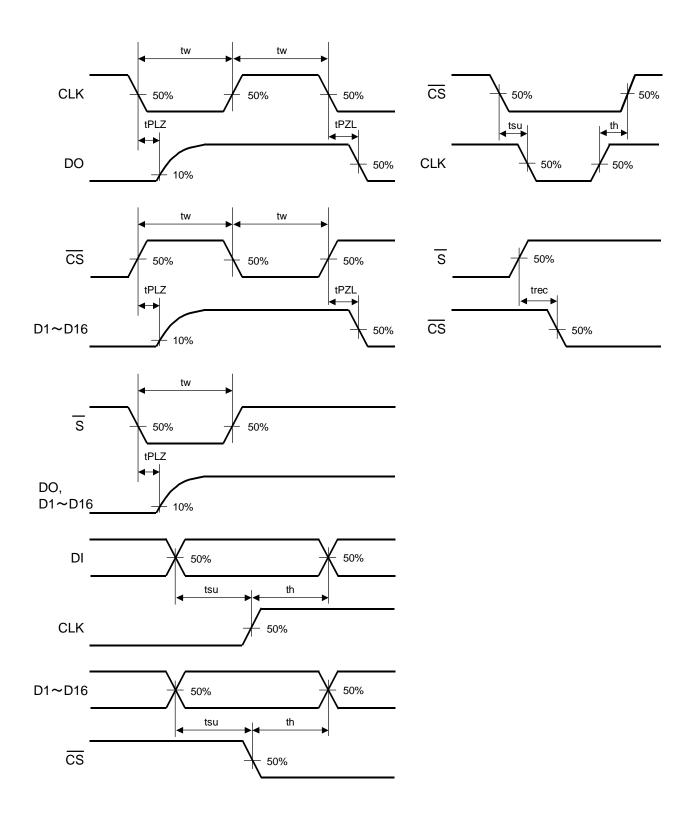
Symbol	Parameter	Test conditions	Limits			Unit
Syllibol			Min.	Тур.	Max.	Offic
tw	CLK, /CS, /S pulse width		260			ns
	Setup time of DI to CLK		130			ns
tsu	Setup time of /CS to CLK		130			ns
	Setup time of D1~D16 to /CS		130			ns
	Hold time of DI to CLK		130			ns
th	Hold time of /CS to CLK		130			ns
	Hold time of D1~D16 to /CS		130			ns
trec	Recovery time of /CS to /S		130			ns

NOTE1: TEST CIRCUIT

- (1) The pulse generator (P.G.) has the following characteristics (10%~90%) tr=6ns, tf=6ns, Zo=50 Ω
- (2) The capacitance CL includes stray wiring capacitance and the probe input capacitance.

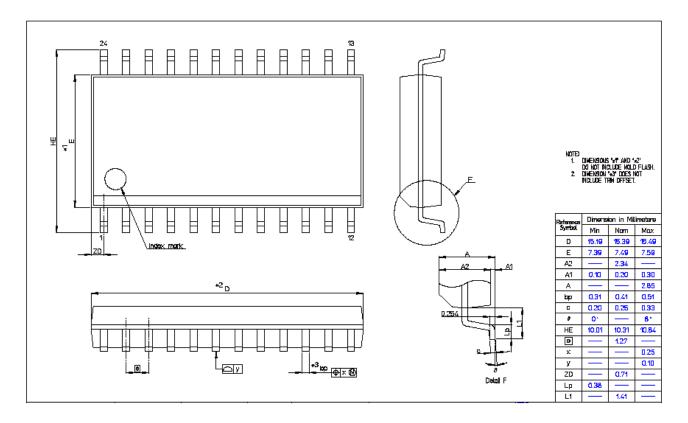


TIMING DIAGRAM



PACKAGE OUTLINE

Package	RENESAS Code	Previous Code	
24pin SOP	PRSP0024DF-A	24P2X-B	



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